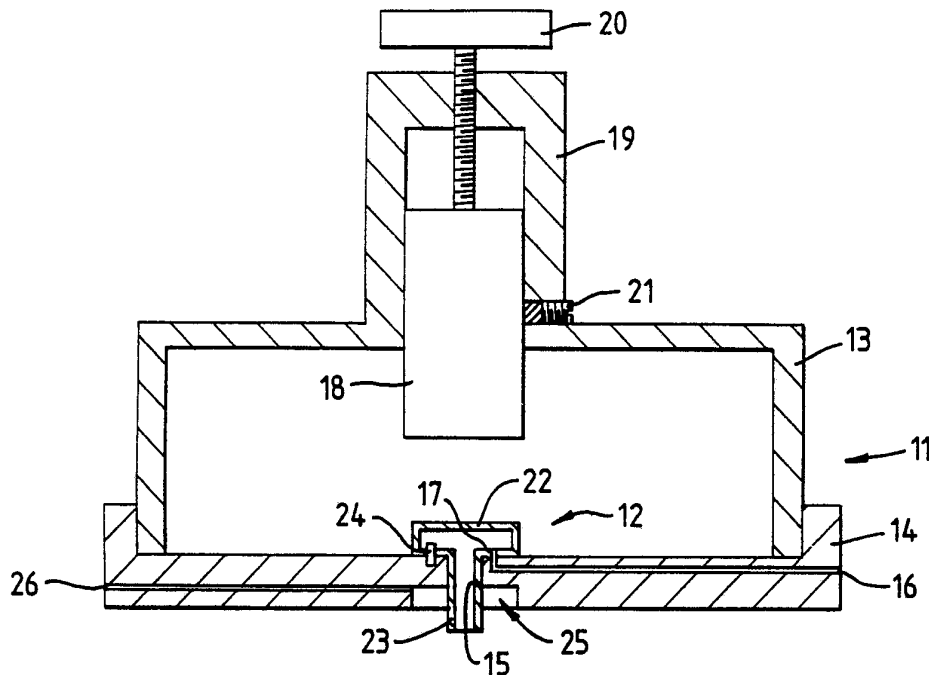




## INTERNATIONAL APPLICATION PUBLISHED UNDER THE PATENT COOPERATION TREATY (PCT)

<p>(51) International Patent Classification <sup>5</sup> : <b>H05H 1/30, 1/46</b></p>	<p><b>A1</b></p>	<p>(11) International Publication Number: <b>WO 92/10077</b> (43) International Publication Date: 11 June 1992 (11.06.92)</p>
<p>(21) International Application Number: PCT/GB91/02086 (22) International Filing Date: 26 November 1991 (26.11.91) (30) Priority data: 9025695.9 27 November 1990 (27.11.90) GB (71) Applicant (for all designated States except US): THE WELDING INSTITUTE [GB/GB]; Abington Hall, Abington, Cambridge CB1 6AL (GB). (72) Inventors; and (75) Inventors/Applicants (for US only) : LUCAS, William [GB/GB]; 6 Spring Close, Burwell, Cambridge CB5 0HF (GB). LUCAS, James [GB/GB]; 12 Sunningdale Drive, Blundell Sands, Liverpool L23 7XA (GB).</p>		<p>(74) Agent: GILL JENNINGS &amp; EVERY; 53/64 Chancery Lane, London WC2A 1HN (GB).  (81) Designated States: AT (European patent), BE (European patent), CH (European patent), DE (European patent), DK (European patent), ES (European patent), FR (European patent), GB (European patent), GR (European patent), IT (European patent), JP, LU (European patent), NL (European patent), SE (European patent), US.  <b>Published</b> <i>With international search report.</i></p>

(54) Title: GAS PLASMA GENERATING SYSTEM



(57) Abstract

A gas plasma generating system comprises a resonant cavity (11) for connection to a source (1) of very high frequency power. A plasma cavity (12) defined by an electrically non-conductive material such as ceramic is positioned within the resonant cavity (11) for containing an ionisable gas such that in use a plasma is formed in the plasma cavity (12), the cavity having an exit opening (23) to enable plasma to exit from the system.

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**GAS PLASMA GENERATING SYSTEM**

The invention relates to a gas plasma generating system for use, for example, in a welding application.

5 It is known that very high frequency electric power can be transmitted via hollow conductors (commonly known as waveguides). The source of such high frequency includes a resonant cavity device such as a magnetron, klystron or free electron laser. Attempts have been made in the past to utilise this very high frequency power to create gas  
10 plasmas. In one arrangement, gas flows along a conduit across which high frequency power is passed. (High Power Microwave Plasma Beam as a Heat Source - Application to Cutting. Arata et al, Transactions of JWRI, Vol 4, No.2 (1975) pp1-6). Although this produces a plasma, the  
15 plasma itself forms a load on the power transmission line and it is necessary to blow the gas at high rate through the conduit to extract the energy. Typical flow rates are in the range 250-400 litres/minute.

In accordance with the present invention, a gas plasma  
20 generating system comprises a resonant cavity for connection to a source of very high frequency power; and a plasma cavity defined by an electrically non-conductive material positioned within the resonant cavity for containing an ionisable gas such that in use a plasma is  
25 formed in the plasma cavity, the cavity having an exit opening to enable plasma to exit from the system.

High frequency discharges at random are known from power supplies operating at very high frequency, where random ionisation has occurred of the surrounding  
30 atmosphere or where there has been inadequate contact between one component and another carrying the very high frequency current. These discharges are uncontrolled and indeed are unwanted since in general they result in significant power loss in a transmission of the very high  
35 frequency current.

We have found that it is possible to harness these previously undesirable discharges so that the very high frequency power can be used to create a gas plasma.

By utilising a non-electrically conductive material to  
5 define the plasma cavity, electrical shorting across the resonant cavity is prevented since the ionising gas is restrained within the plasma cavity. Typically, the plasma cavity is confined by a ceramic wall.

The space within the resonant cavity surrounding the  
10 plasma cavity is filled with an insulating gas which is preferably air since this is particularly good for cooling.

It has been found with the invention that gas flows as low as of one litre/minute are achievable.

In this context, by very high frequency we mean  
15 generally frequencies in excess of 100 MHz and preferably in excess of 1 GHz, even in excess of 10 GHz. In this latter range, the tuned cavity dimensions are of the order of tens of millimetres while the exiting plasma can be used for heating, surface treatment, welding or cutting as are  
20 known at comparatively low frequencies or with DC in the field of welding technology.

Preferably, the resonant cavity is tunable. For example, the cavity may include a movable tuning member whose position can be adjusted to achieve the desired  
25 tuning condition. In this case, the plasma cavity may comprise a generally tubular member extending through the tuning member.

The tuning member will typically comprise a tuning stub. In some cases an additional fine tuning member will  
30 also be provided.

In an alternative arrangement, however, the source of very high frequency power could be tunable or indeed both the source and resonant cavity could be tunable. By providing at least one tunable component it is possible to  
35 optimize both the striking and the running of the discharge. It should be noted that before the discharge is established, the resonant cavity is in effect

open-circuited. During use, retuning of the source or cavity is preferably carried out so that a high current flows through the plasma discharge to provide heating and ionization of the gases forming the discharge.

5           Any conventional source of high frequency power could be used such as a magnetron, klystron or free electron laser. The power can be supplied from the source to the resonant cavity via wave guides, coaxial lines or equivalent.

10           In one particular arrangement the wave guide may be a flexible wave guide with an end termination producing a standing wave forming a node at a short distance from the end where the desired discharge such as an arc is to be located. In another arrangement the cavity and wave guide  
15           may be in the form of a doughnut ring with the very high frequency generator at one position and the desired discharge at nominally a diametrically opposite position in the ring.

          In the preferred embodiment, a tunable, very high  
20           frequency generator is utilised together with a suitable wide band amplifier for feeding the connecting wave guide and cavity between the generator and the cavity containing the discharge. An objective of the tunable arrangement is readily to change the effective field distribution  
25           characteristics of the wave guide or cavity with respect to the region of the discharge, so that at one stage a hypertensial (E mode) is developed and at another stage a high current (H mode) is obtained in the discharge. This transition may be controlled via a high speed digital  
30           computer or dedicated digital control system with a transducer detecting the events in the vicinity of the discharge, so that the high voltage is maintained until breakdown occurs and thereafter the high current stage is induced. Alternatively, the change-over may be pre-timed  
35           so that the high voltage is maintained for a finite period, thereafter the system reverts to the high current stage for maintaining the discharge so established.

The wave guide may be shaped to produce specific field patterns in the vicinity or desired region for the discharge in order to enhance the striking of the discharge or its maintenance after breakdown.

5 The plasma cavity will be supplied in use with preferably an inert gas or a substantially inert gas.

Suitable dielectrics for support members and other non-conducting components including the plasma cavity are quartz, boron nitride, alumina and machinable ceramics  
10 because of their low loss characteristics at high frequency.

The invention has a number of different applications. The high frequency electric plasma discharge itself could be used for heating, welding or cutting materials or could  
15 be used to maintain a known electric arc system for the purposes of heating, welding or cutting materials, particularly metals. This will be described in more detail below. However, it should be noted that, under suitable  
20 conditions, the introduction of the very high frequency plasma allows a low frequency discharge to be maintained with low values of alternating current without the necessity either for high circuit voltages or for the injection of restriking voltages in the region of current zero.

25 The high frequency may also be used to preheat the wire in MIG welding or the separate wire feed as in the TIG-hot process. In either case, heating of the wire will take place prior to it entering the arc.

Some examples of gas plasma generating systems  
30 according to the invention will now be described with reference to the accompanying drawings, in which:-

Figure 1 is a block diagram of a complete system;

Figure 2 illustrates an example of the resonant and plasma cavities in more detail; and,

35 Figure 3 illustrates the resonant and plasma cavities of a second example.

The gas plasma generating system shown in Figure 1 comprises a very high frequency source 1 such as a magnetron or klystron coupled via wave guides or coaxial cable 6 to a resonant or tuning cavity 2. An isolation system 3 is provided between the source 1 and the cavity 2 to prevent reflected power returning to the source 1, while a transmitted power meter 4 and reflected power meter 5 are positioned between the source 1 and the isolation system 3.

The resonant cavity 2 is only shown schematically in Figure 1. Figure 1 illustrates the presence of a primary, coarse tuning stub 7 having an external screw thread allowing it to be adjusted inwardly and outwardly of the resonant cavity 2. A fine tuning stub 8 is also provided to enable fine tuning to be achieved. A plasma cavity 9 is positioned in the resonant cavity 2, the cavity 9 having an opening 10 positioned in alignment with a corresponding opening within the wall of the resonant cavity 2.

Figure 2 illustrates an example of a resonant cavity 11 and plasma cavity 12 in more detail. The resonant cavity 11 has walls defined by conducting material such as brass and comprises a main body portion 13 with a generally circular cross-section. The main body portion is closed on its lower side by a plate 14 which defines a plasma exit opening 15 for the plasma cavity 12 to be described below. The plate 14 also includes a conduit 16 for the supply of gas to the plasma cavity 12 through an orifice 17. The resonant cavity 11 is tunable by means of an axially movable, cylindrical block 18 mounted in a housing 19 to the main body portion 13. The block 18 can be moved into and out of the cavity 11 by turning a screw-threaded connector 20. A sprung contact plug 21 ensures good contact between the block 18 and the housing 19.

The plasma cavity 12 which is located at the exit opening 15 of the resonant cavity 11 has a circular cross section and is defined by an upper, ceramic part 22 which is secured to a ceramic nozzle section 23. A typical

dimension for the ceramic part 22 is a diameter of 7mm and a height of 3mm. Gas is supplied from the conduit 16 in the plate 14 to the cavity 12. Plasma exits from the cavity 12 through the nozzle section 23. A tungsten electrode 24 is mounted within the plasma cavity 12.

A separate shielding gas flow is fed to a region 25 surrounding the nozzle 23 through a conduit 26 in the plate 14. The gas is typically argon or argon-hydrogen and is used to cool the nozzle 23 and to provide protection of the weld pool and surrounding metal during welding and surface treatment or to assist in cutting.

The plasma gas supplied through the conduit 16 is preferably an inert gas with an admixture of a diatomic gas to increase the power dissipated in the discharge. For example, argon with hydrogen provides a discharge capable of heating for surface treatment or melting or cutting metals placed in the vicinity of the plasma outflow from the orifice. The hydrogen content can be substantially increased, but preferably it does not exceed 40% in order to maintain a stable running discharge. Other gases include helium for welding and nitrogen and air for cutting.

The rate at which gas is flowed through the conduit 16, must be such as to enable ionisation to be achieved but not so high that the gas is cooled. For a 200 W source 1, a flow rate of 1 litre/minute has been found to be suitable.

Another example is shown in Figure 3 in which a plasma cavity 27 is defined by a tubular ceramic member extending through opposed sides of a resonant cavity 29. On one side, the tubular member passes through an aperture 28 in a wall of the resonant cavity 29 while on the opposite side the tubular member passes through a tuning stub 30 screw-threaded into an aperture 31 in the resonant cavity 29. An electrode 32 extends into the tubular member 27. Plasma gas is supplied into the upper opening 33 of the tubular member 27 which, since it extends throughout the

resonant cavity 29, prevents the plasma from forming a short circuit between the tuning stub 30 and the resonant cavity wall. The plasma exits through the end 34 of the ceramic tube 27. A typical bore diameter of the ceramic tube 27 is 3 mm and the gas flow is typically 1litre/minute at 200 W power. Shielding gas is supplied, as before, through a conduit 35 to the region 36 surrounding the exit of the ceramic tube 27. The advantage of the Figure 3 construction is that it enables a simple ceramic tube to be used both to feed the plasma gas and to form the plasma.

The power of the high frequency generator 1 may be of the order 500-1000 W or higher as desired. Such high frequency generators are commonly used in the microwave industry for heating foodstuffs and the like and for curing wood and adhesives, and so forth. To enhance the power in the discharge for purposes of heat treatment, welding and cutting of materials, further electric supplies can be introduced. For example, a connection may be made to the workpiece and the probe electrode which is placed in contact with the plasma inside the cavity.

Alternatively, a separate power discharge can be arranged on the output side of the plasma outlet with, say, an electrode (eg. a Tg electrode) penetrating into the plasma stream, together with the workpiece. Power is supplied to the auxiliary electrode and workpiece to increase the intensity of the output discharge for treatment of metals, heating, welding and cutting. In a preferred arrangement the auxiliary electrode is electrically connected to the plasma cavity (input or gas output) so that it is at a similar potential. Low frequency AC or DC supplies may be utilised in conjunction with the continuous high frequency discharge without substantially interfering with the operation of the latter.

A modification of this enhancement is shown in Figure 3. A voltage source 37 is connected between the electrode 32 and a workpiece 38 carried on a support 39.

Alternatively, the high frequency power may be used to ignite an AC/DC arc, the high frequency being reduced or turned off immediately following the connection of the auxiliary power circuit. Yet again, the high frequency may be switched off just before the auxiliary circuit is connected. Interlock electromechanical means may be utilised to ensure proper sequence of operations so that the high frequency is used to initiate a discharge which is thereafter maintained by conventional DC or low frequency AC power circuits. The enhanced discharge can comprise an arc discharge from a tungsten electrode such as in TIG or plasma arc welding or it may comprise a relatively thin wire which is melted and consumed by the enhanced discharge as in MIG arc welding. The low frequency or DC current in such a discharge may be maintained at a steady level or alternatively operated in sequence at more than one level, as is known in pulsed welding current. The gases used in the enhanced discharge may be typical of those used in TIG and MIG arc welding or in plasma welding and cutting, such as inert or substantially inert gases composed of argon, helium or admixtures thereof together with limited additions of other gases such as hydrogen or oxygen, as is well known. For cutting, the gas can be either argon-H<sub>2</sub>, nitrogen or air but special electrode material such as hafnium tipped copper electrode will be required. Furthermore, oxidising gas atmospheres especially for MIG welding may be used, such as CO<sub>2</sub> or admixtures of inert gas with CO<sub>2</sub> and similar mixtures with small additions of oxygen, and so forth. These gases are well known in the field of welding and cutting technology and are not a specific part of the present invention.

These and other variations can be adapted wherever feasible in association with the high frequency discharge from an unconnected probe electrode.

CLAIMS

1. A gas plasma generating system comprising a resonant cavity for connection to a source of very high frequency power; and a plasma cavity defined by an electrically non-conductive material positioned within the resonant cavity for containing an ionisable gas such that in use a plasma is formed in the plasma cavity, the cavity having an exit opening to enable plasma to exit from the system.  
5
2. A system according to claim 1, wherein the plasma cavity comprises a first section positioned within the resonant cavity, and a second, nozzle section communicating with the first section and extending through an aperture in the resonant cavity.  
10
3. A system according to claim 2, further comprising means to enable a plasma gas to be supplied to the first section of the plasma cavity.  
15
4. A system according to claim 3, wherein the means includes a conduit extending through a wall of the resonant cavity.
- 20 5. A system according to claim 1, wherein the plasma cavity comprises a tubular member extending through opposed walls of the resonant cavity, the tubular member receiving at one end a plasma gas, in use, and plasma exiting from the other end.
- 25 6. A system according to any of the preceding claims, further comprising a movable tuning member whose position can be adjusted to achieve the desired tuning condition.
7. A system according to claim 6, when dependent on claim 5, wherein the tubular member defining the plasma cavity extends through the tuning member.  
30
8. A system according to any of the preceding claims, wherein the plasma cavity is defined by a ceramic wall.
9. A system according to any of the preceding claims, further comprising means for supplying a shielding gas to  
35 a region surrounding an exit portion of the plasma cavity.

10. A system according to claim 9, wherein the means includes a conduit extending through a wall of the resonant cavity.

5 11. Welding apparatus including a gas plasma generating system according to any of the preceding claims.

12. Welding apparatus according to claim 11, further comprising an electrode positioned in use in the plasma; and means for generating a voltage between the electrode and a workpiece.

Fig.1.

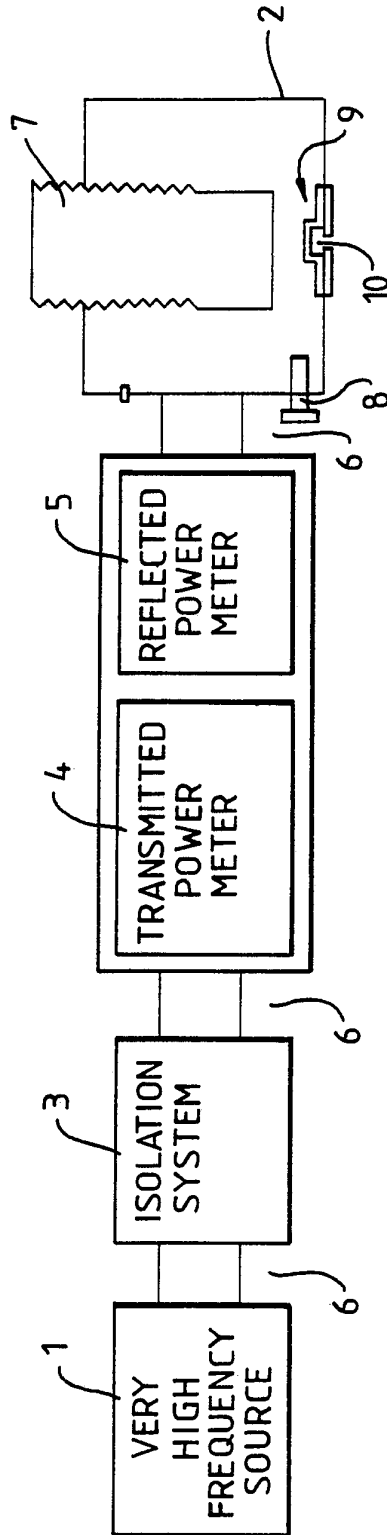


Fig. 2.

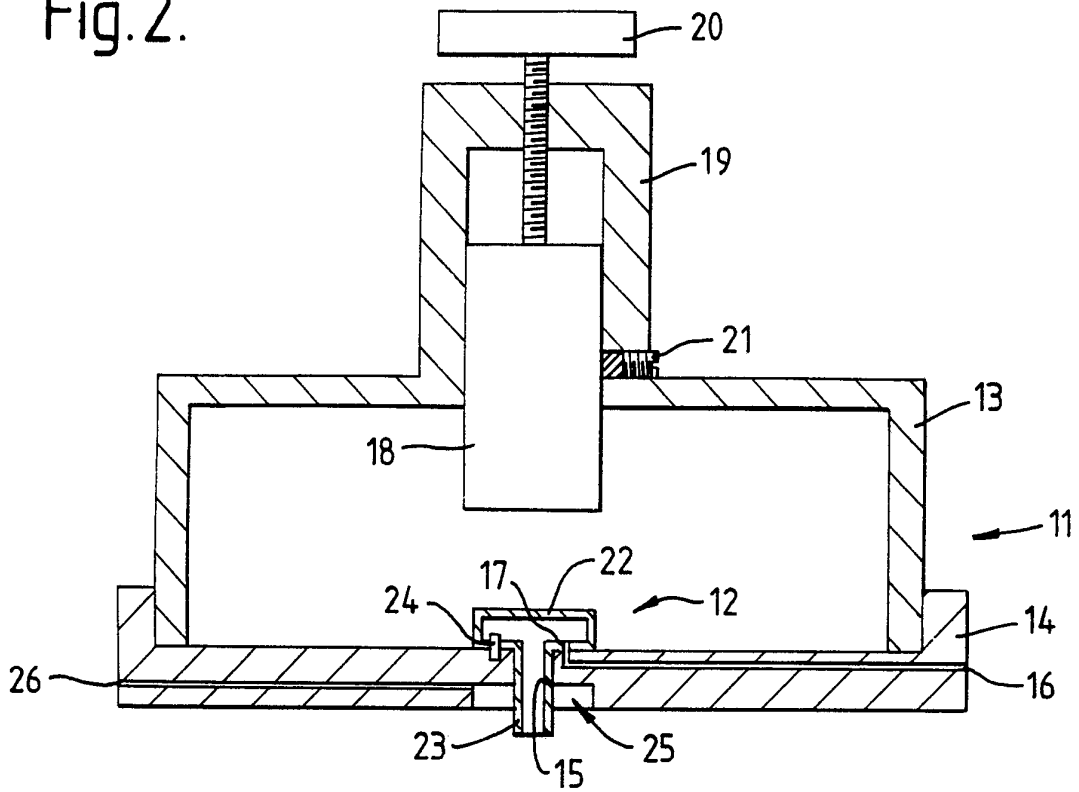
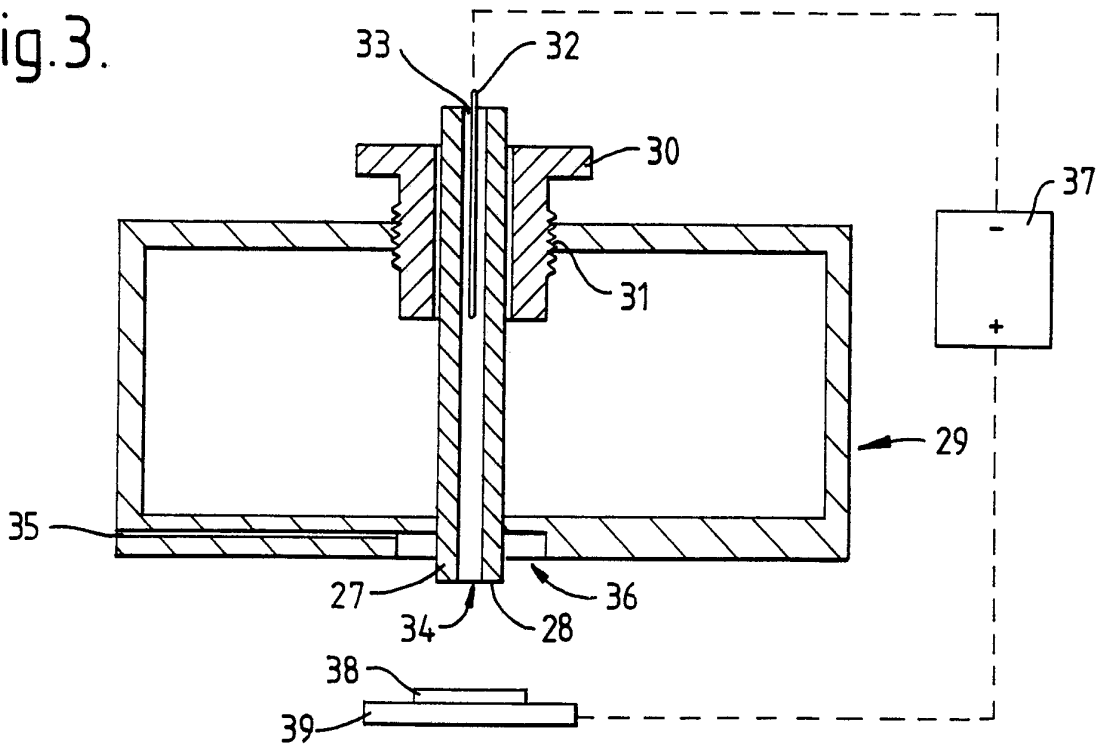


Fig. 3.



# INTERNATIONAL SEARCH REPORT

International Application No

PCT/GB 91/02086

<b>I. CLASSIFICATION OF SUBJECT MATTER</b> (if several classification symbols apply, indicate all) <sup>6</sup>		
According to International Patent Classification (IPC) or to both National Classification and IPC Int.C1. 5 H05H1/30;                      H05H1/46		
<b>II. FIELDS SEARCHED</b>		
Minimum Documentation Searched <sup>7</sup>		
Classification System	Classification Symbols	
Int.C1. 5	H05H	
Documentation Searched other than Minimum Documentation to the Extent that such Documents are Included in the Fields Searched <sup>8</sup>		
<b>III. DOCUMENTS CONSIDERED TO BE RELEVANT<sup>9</sup></b>		
Category <sup>o</sup>	Citation of Document, <sup>11</sup> with indication, where appropriate, of the relevant passages <sup>12</sup>	Relevant to Claim No. <sup>13</sup>
X	JOURNAL OF VACUUM SCIENCE AND TECHNOLOGY: PART B. vol. 4, no. 1, January 1986, NEW YORK US pages 295 - 298; ROPPEL ET AL.: 'Low temperature oxidation of silicon using a microwave plasma disk source' see Chapters 1-2 see figure 1B  ---	1,6
A	WO,A,8 810 506 (APPLIED SCIENCE & TECHNOLOGY) 29 December 1988 see page 15, last paragraph - page 16, last paragraph see figures 4,6  ---	1-4,6
A	EP,A,0 321 792 (HEWLETT-PACKARD) 28 June 1989 see page 3, line 26 - line 57 see figure 1  ---	5
-/--		
<div style="display: flex; justify-content: space-between;"> <div style="width: 45%;"> <p><sup>o</sup> Special categories of cited documents : <sup>10</sup></p> <p>"A" document defining the general state of the art which is not considered to be of particular relevance</p> <p>"E" earlier document but published on or after the international filing date</p> <p>"L" document which may throw doubts on priority claim(s) or which is cited to establish the publication date of another citation or other special reason (as specified)</p> <p>"O" document referring to an oral disclosure, use, exhibition or other means</p> <p>"P" document published prior to the international filing date but later than the priority date claimed</p> </div> <div style="width: 45%;"> <p>"T" later document published after the international filing date or priority date and not in conflict with the application but cited to understand the principle or theory underlying the invention</p> <p>"X" document of particular relevance; the claimed invention cannot be considered novel or cannot be considered to involve an inventive step</p> <p>"Y" document of particular relevance; the claimed invention cannot be considered to involve an inventive step when the document is combined with one or more other such documents, such combination being obvious to a person skilled in the art.</p> <p>"&amp;" document member of the same patent family</p> </div> </div>		
<b>IV. CERTIFICATION</b>		
Date of the Actual Completion of the International Search	Date of Mailing of this International Search Report	
11 FEBRUARY 1992	20 FEB 1992	
International Searching Authority	Signature of Authorized Officer	
EUROPEAN PATENT OFFICE	E. CAPOSTAGNO	

III. DOCUMENTS CONSIDERED TO BE RELEVANT (CONTINUED FROM THE SECOND SHEET)		Relevant to Claim No.
Category °	Citation of Document, with indication, where appropriate, of the relevant passages	
A	EP,A,0 043 740 (ANVAR) 13 January 1982 see page 3, line 38 - page 5, line 38 see figure 1  ---	5

**ANNEX TO THE INTERNATIONAL SEARCH REPORT  
ON INTERNATIONAL PATENT APPLICATION NO. GB 9102086  
SA 53514**

This annex lists the patent family members relating to the patent documents cited in the above-mentioned international search report. The members are as contained in the European Patent Office EDP file on  
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Patent document cited in search report	Publication date	Patent family member(s)	Publication date
WO-A-8810506	29-12-88	US-A- 4866346	12-09-89
		EP-A- 0318539	07-06-89
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